

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Bridge Rectifiers
- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V_{DRM} and V_{RRM} (V)	Conditions
DCR6140H42	4200	$T_{vj} = -40^{\circ}\text{C}$ to 125°C , $I_{DRM} = I_{RRM} = 600\text{mA}$, $V_{DRM}, V_{RRM} t_p = 10\text{ms}$ $V_{DSM} \ \& \ V_{RSM} =$ $V_{DRM} \ \& \ V_{RRM} + 100\text{V}$ respectively
DCR6140H40	4000	
DCR6140H38	3800	

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR6140H42

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{DRM}	4200V
$I_{T(AV)}$	6070A
I_{TSM}	90000A
dV/dt^*	2000V/μs
dI/dt	500A/μs

* Higher dV/dt selections are available on request

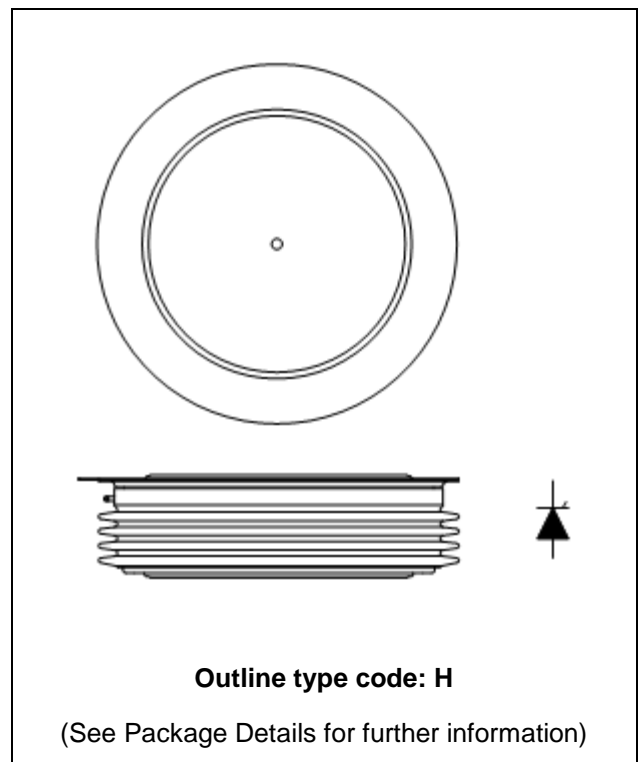


Fig. 1 Package outline

CURRENT RATINGS

$T_{case} = 60^{\circ}C$ unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	6070	A
$I_{T(RMS)}$	RMS value	-	9530	A
I_r	Continuous (direct) on-state current	-	8350	A

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$ $V_R = 0$	90.0	kA
I^2t	I^2t for fusing		40.5	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	DC	-	4.3	$^{\circ}C/kW$
		Single side cooled	Anode DC	-	8.0	$^{\circ}C/kW$
			Cathode DC	-	9.5	$^{\circ}C/kW$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 135kN (with mounting compound)	Double side	-	0.9	$^{\circ}C/kW$
			Single side	-	1.8	$^{\circ}C/kW$
T_{vj}	Virtual junction temperature	Blocking V_{DRM} / V_{RRM}	-	125	$^{\circ}C$	
T_{stg}	Storage temperature range		-55	125	$^{\circ}C$	
F_m	Clamping force		120	155	kN	

DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
I_{RRM}/I_{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C	-	600	mA	
V_{TM}	Instantaneous forward voltage	At 4000A peak, T _j = 125°C	1.25	1.40	V	
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, gate open	-	2000	V/μs	
dI/dt	Rate of rise of on-state current	From 67% V _{DRM} to 2x I _{T(AV)} Gate source 30V, 10Ω tr < 0.5μs, T _j = 125°C	Repetitive 50Hz	-	200	A/μs
			Non-repetitive	-	500	A/μs
V_{T(TO)}	Threshold voltage - Low level	1000A to 4200A at T _{case} = 125°C	-	0.86	V	
	Threshold voltage - High level	4200A to 9000A at T _{case} = 125°C	-	1.07	V	
r_T	On-state slope resistance - low level	1000A to 4200A at T _{case} = 125°C	-	0.14	mΩ	
	On-state slope resistance - High level	4200A to 9000A at T _{case} = 125°C	-	0.09	mΩ	
t_{gd}	Delay time	V _D = 67% V _{DRM} , gate source 30V, 10Ω tr = 0.5μs, T _j = 25°C	-	3	μs	
t_q	Turn-off time	I _T = 3000A, T _j = 125°C, V _R = 200V, dI/dt = 1A/μs, dV _{DR} /dt = 20V/μs linear	-	700	μs	
Q_s	Stored charge	I _T = 3000A, T _j = 125°C, dI/dt = 1A/μs	1500	3800	μC	
I_{RR}	Reverse recovery current	V _{R(peak)} ~ 2500V, V _{RM} ~ 1700V	32	49	A	
I_L	Latching current	T _j = 25°C, V _D = 5V	-	3	A	
I_H	Holding current	T _j = 25°C, R _{G-K} = ∞, I _{TM} = 500A, I _T = 5A	-	300	mA	

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	1.5	V
V_{GD}	Gate non-trigger voltage	At 50% $V_{DRM}, T_{case} = 125^{\circ}C$	0.4	V
I_{GT}	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	350	mA
I_{GD}	Gate non-trigger current	At 50% $V_{DRM}, T_{case} = 125^{\circ}C$	10	mA

CURVES

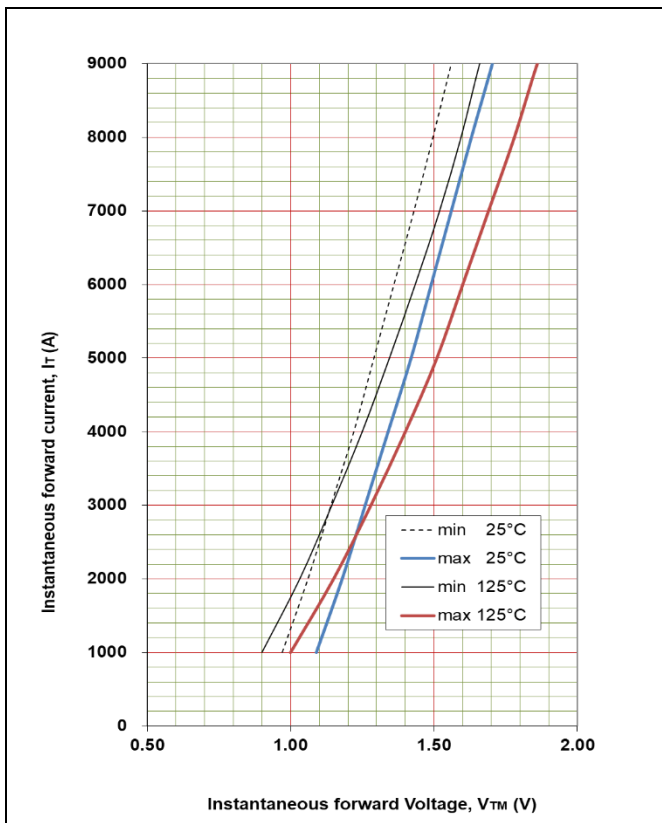


Fig. 2 Maximum & minimum on-state characteristics

V_{TM} EQUATION

$$V_{TM} = A + B \cdot \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

Where $A = 1.127626$

$B = -0.090667$

$C = 0.000011$

$D = 0.015417$

These values are valid for $T_j = 125^{\circ}C$ for I_T 1000A to 9000A

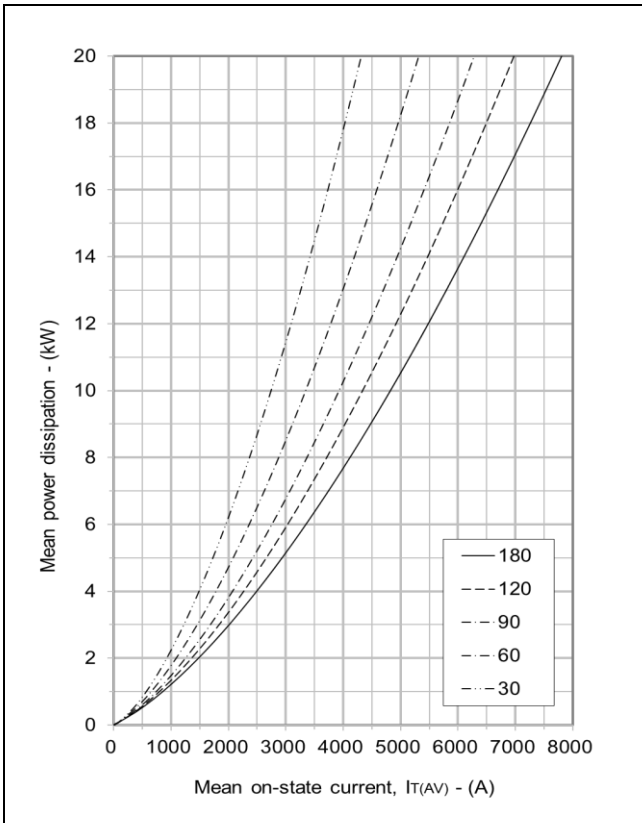


Fig. 3 On-state power dissipation - sine wave

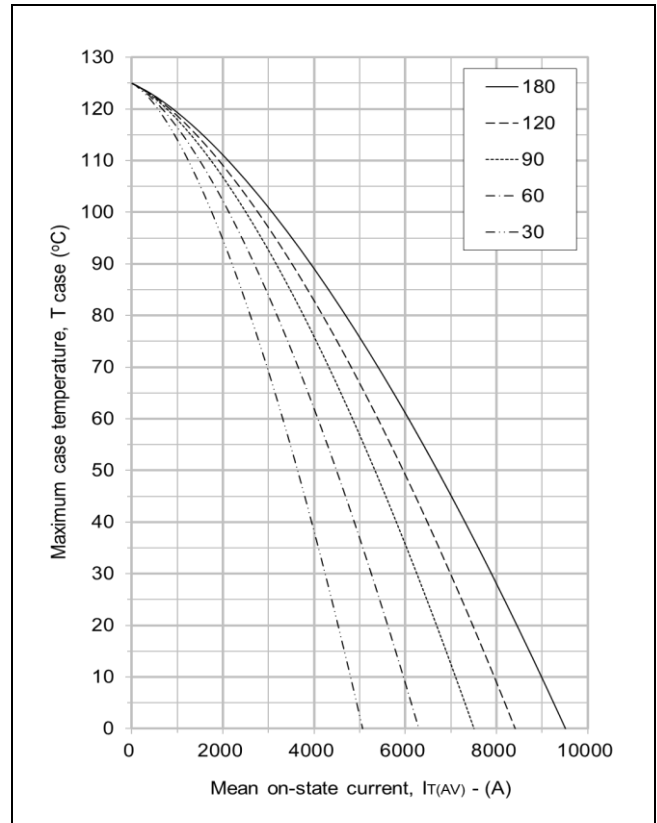


Fig. 4 Maximum permissible case temperature, double side cooled - sine wave

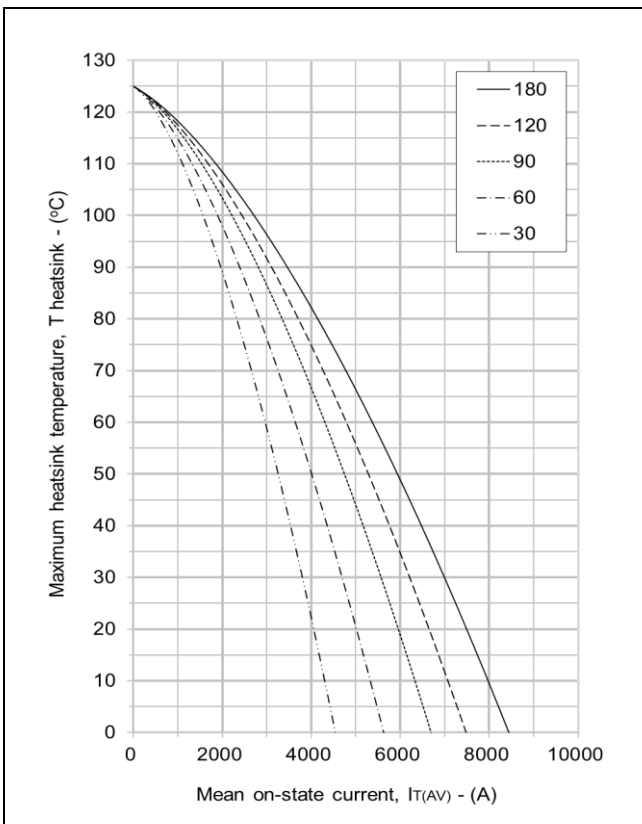


Fig. 5 Maximum permissible heatsink temperature, double side cooled - sine wave

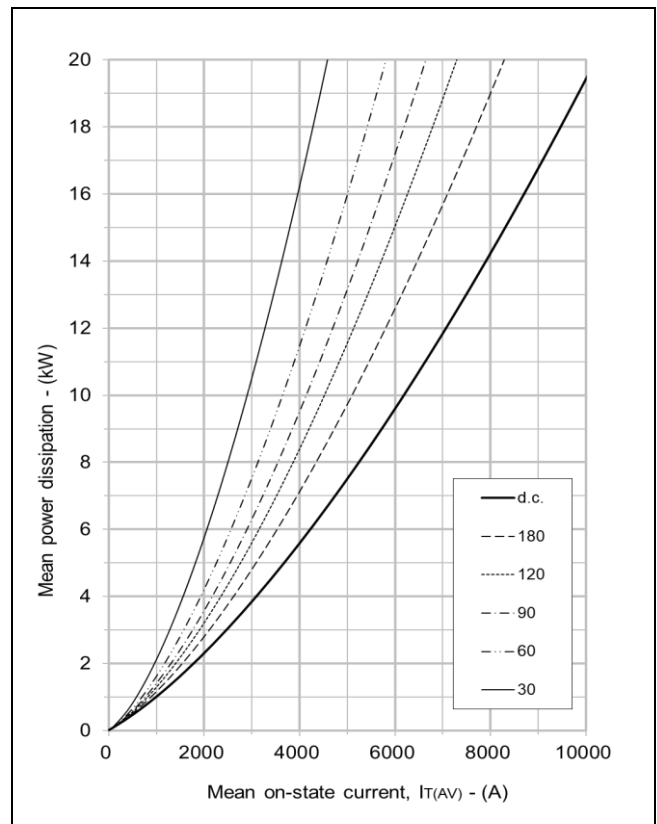


Fig. 6 On-state power dissipation - rectangular wave

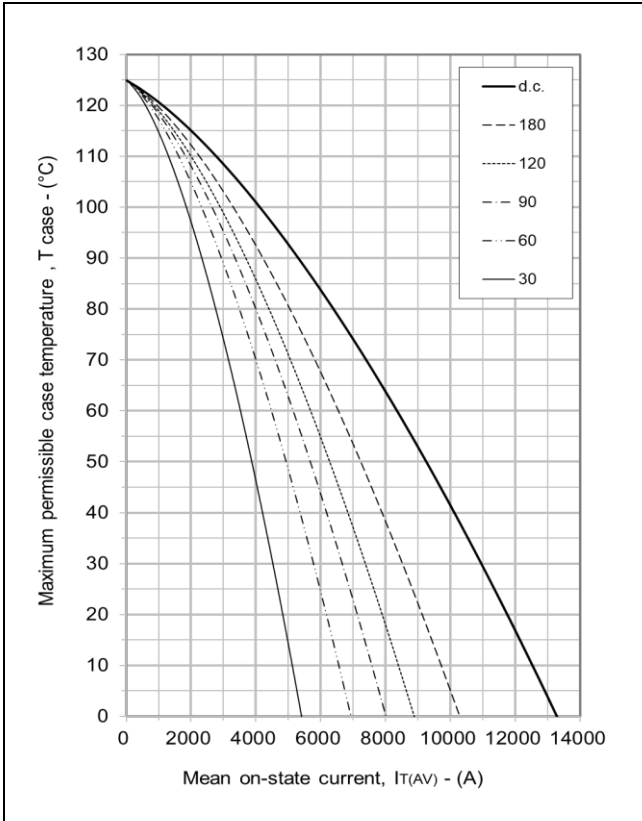


Fig. 7 Maximum permissible case temperature, double side cooled - rectangular wave

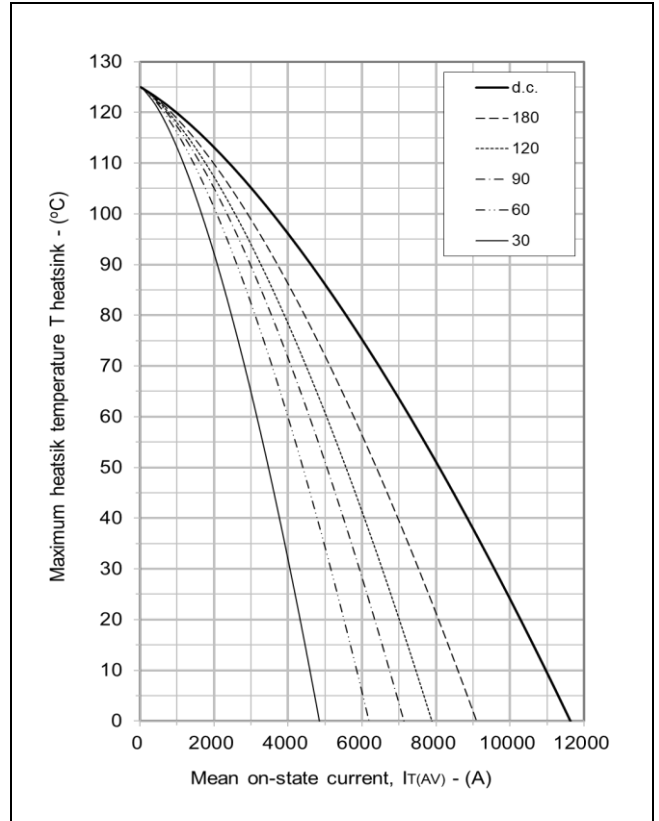


Fig. 8 Maximum permissible heatsink temperature, double side cooled - rectangular wave

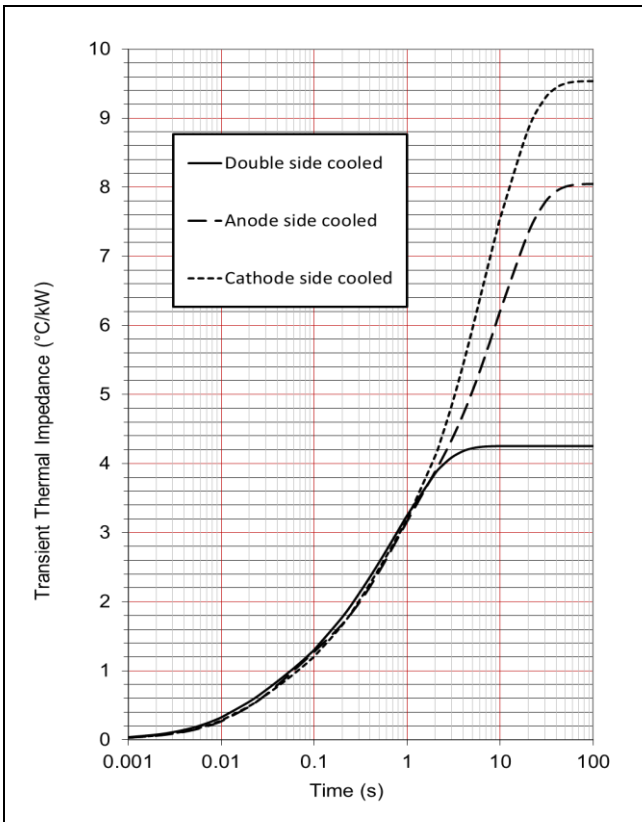


Fig. 9 Maximum (limit) transient thermal impedance – junction to case (degC/kW)

		1	2	3	4
Double side cooled	Ri(°C/kW)	1.248	0.833	0.606	1.568
	Ti(s)	0.670	0.146	0.020	1.287
Anode side cooled	Ri(°C/kW)	0.512	1.946	0.920	4.666
	Ti(s)	2.898	0.505	0.036	10.647
Cathode side cooled	Ri(°C/kW)	2.417	1.537	0.626	4.959
	Ti(s)	3.441	0.269	0.024	10.172

$$Z_{th} = \sum_{i=1}^{i=4} R_i \cdot \left(1 - \exp\left(-\frac{T}{T_i}\right)\right)$$

$\Delta R_{th(j-c)}$ Conduction

Tables show the increments of thermal resistance $R_{th(j-c)}$ when the device operates at conduction angles other than d.c.

Double side cooling			Anode Side Cooling			Cathode Sided Cooling		
θ°	$\Delta Z_{th}(z)$		θ°	$\Delta Z_{th}(z)$		θ°	$\Delta Z_{th}(z)$	
	sine.	rect.		sine.	rect.		sine.	rect.
180	0.38	0.26	180	0.32	0.23	180	0.33	0.23
120	0.44	0.37	120	0.36	0.31	120	0.38	0.33
90	0.49	0.43	90	0.41	0.36	90	0.43	0.37
60	0.54	0.49	60	0.45	0.40	60	0.47	0.43
30	0.58	0.55	30	0.48	0.45	30	0.51	0.48
15	0.60	0.58	15	0.49	0.48	15	0.52	0.51

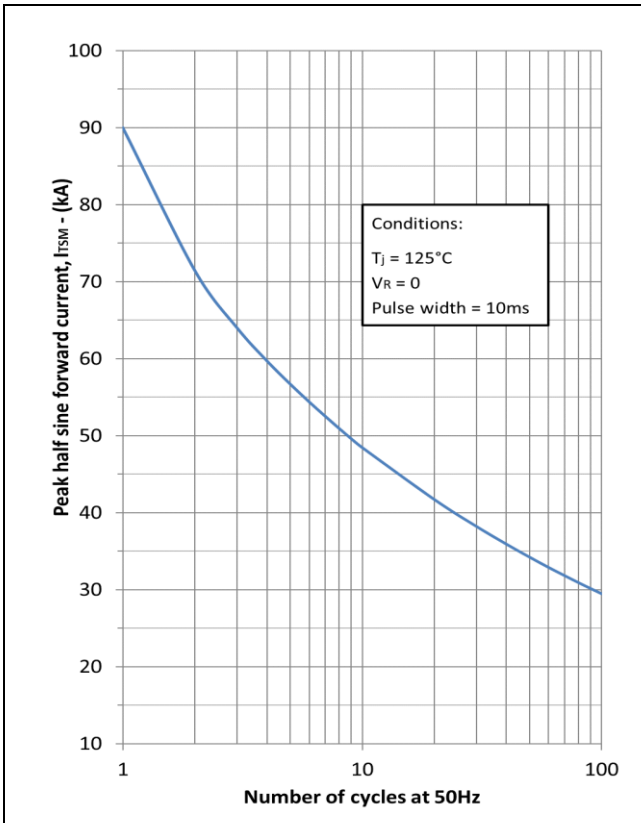


Fig. 10 Multi-cycle surge current

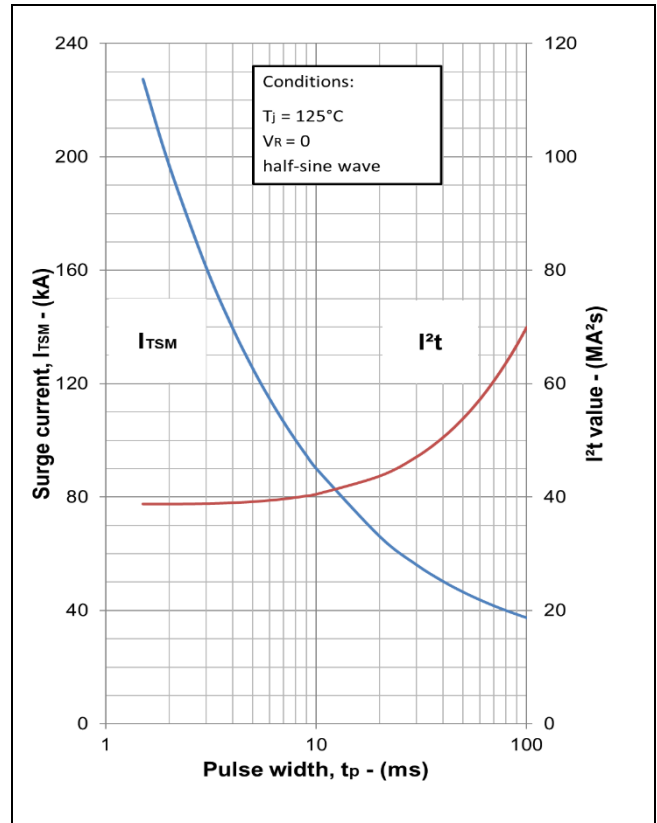


Fig. 11 Single-cycle surge current

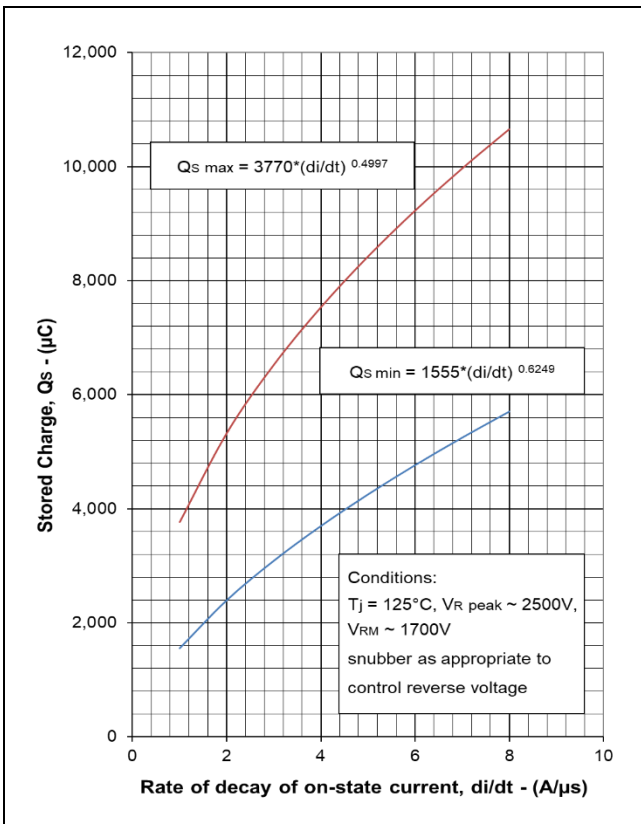


Fig. 12 Reverse recovery charge

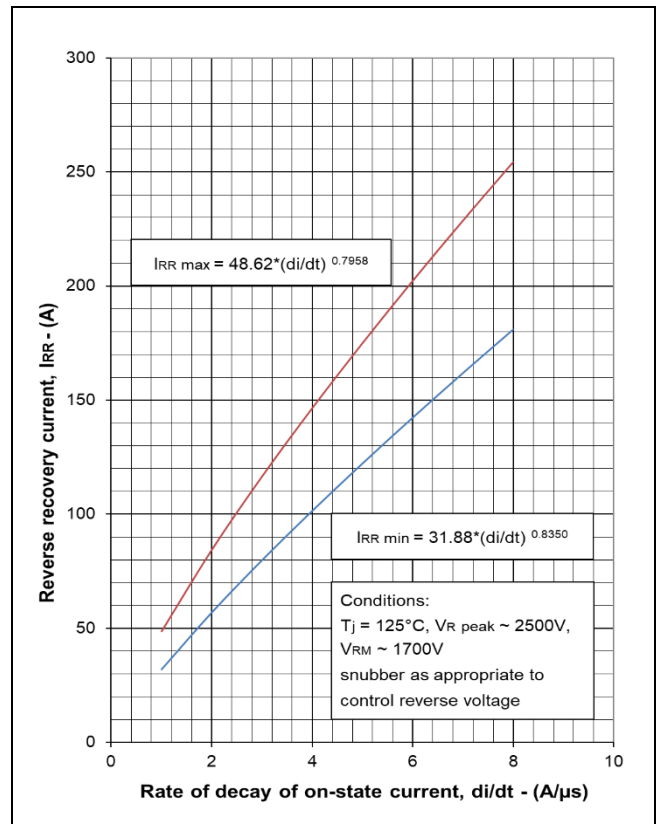


Fig. 13 Reverse recovery current

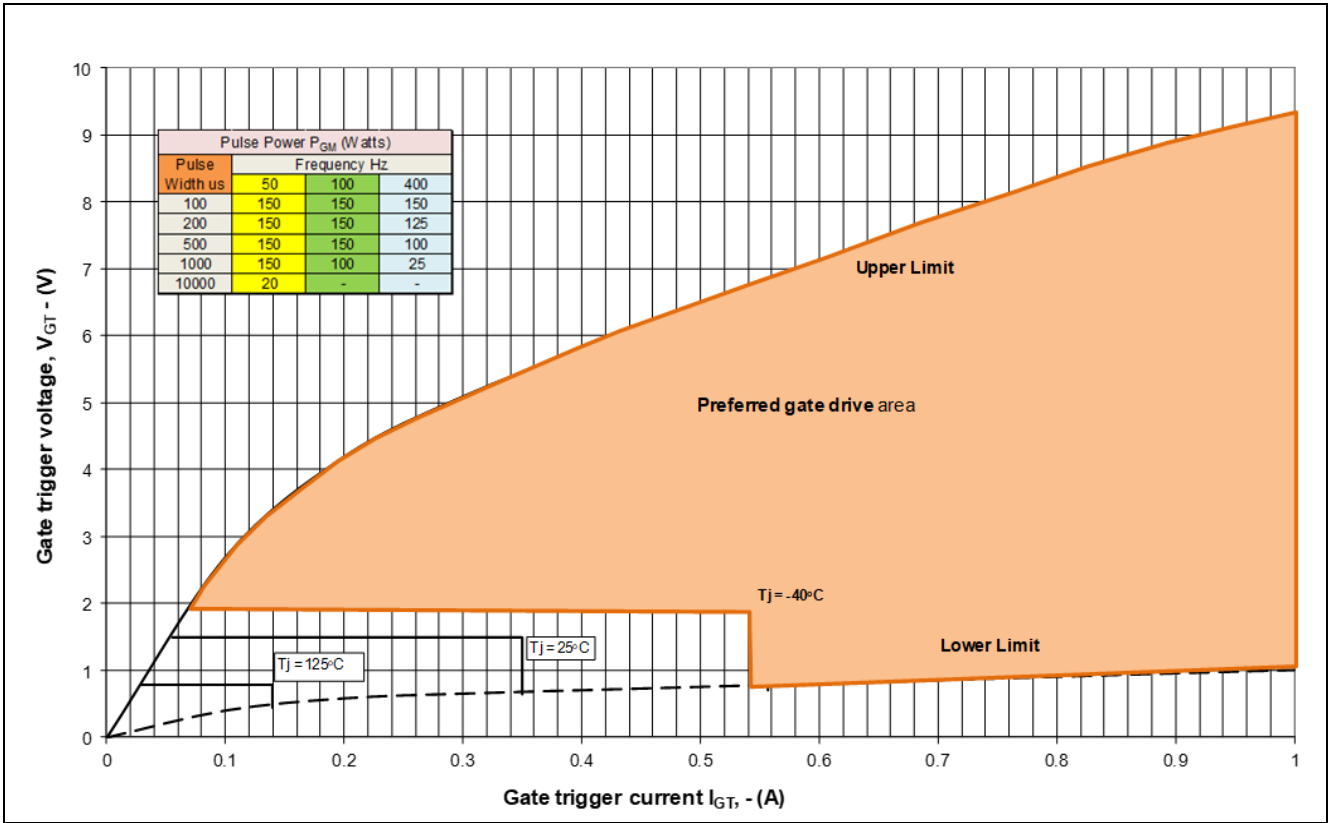


Fig. 14 Gate characteristics

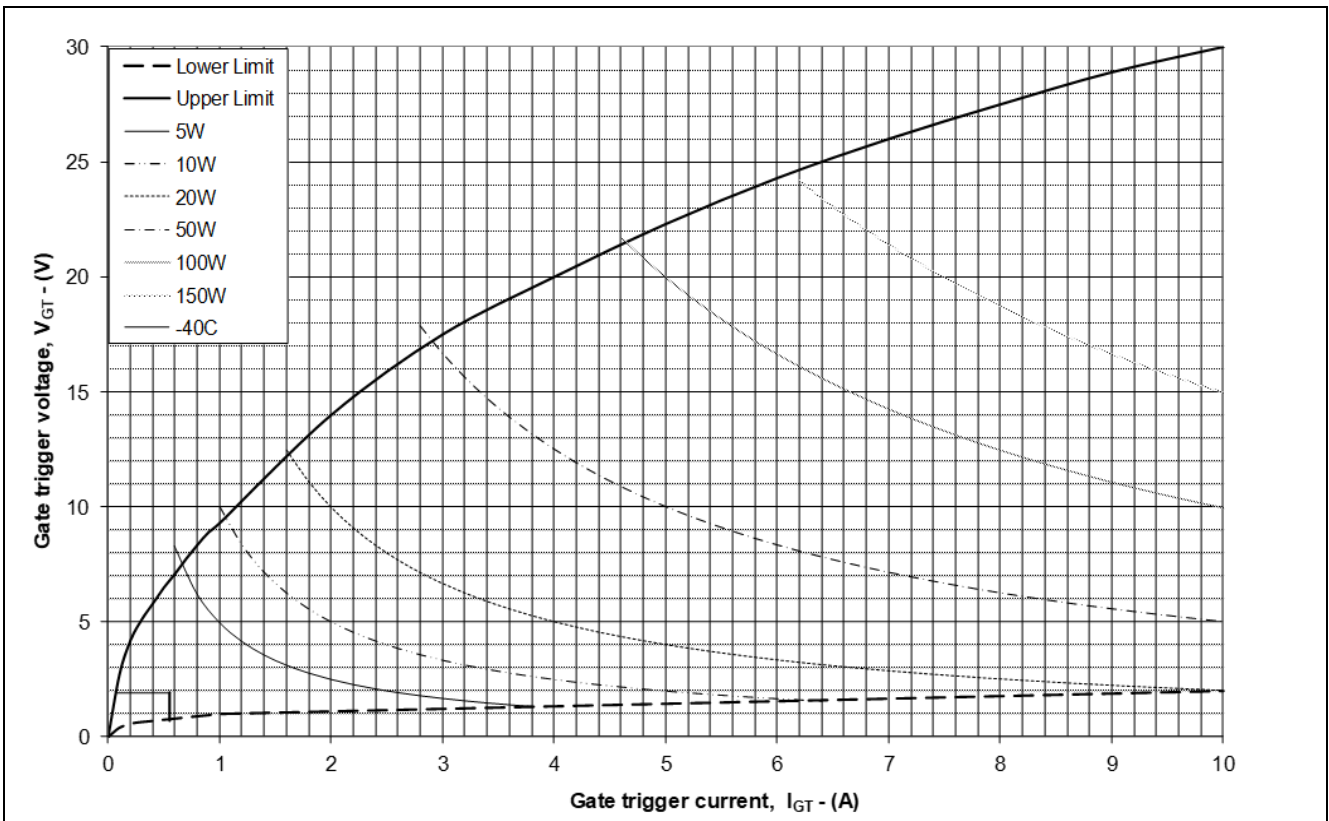


Fig. 15 Gate characteristics

PACKAGE DETAILS

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE

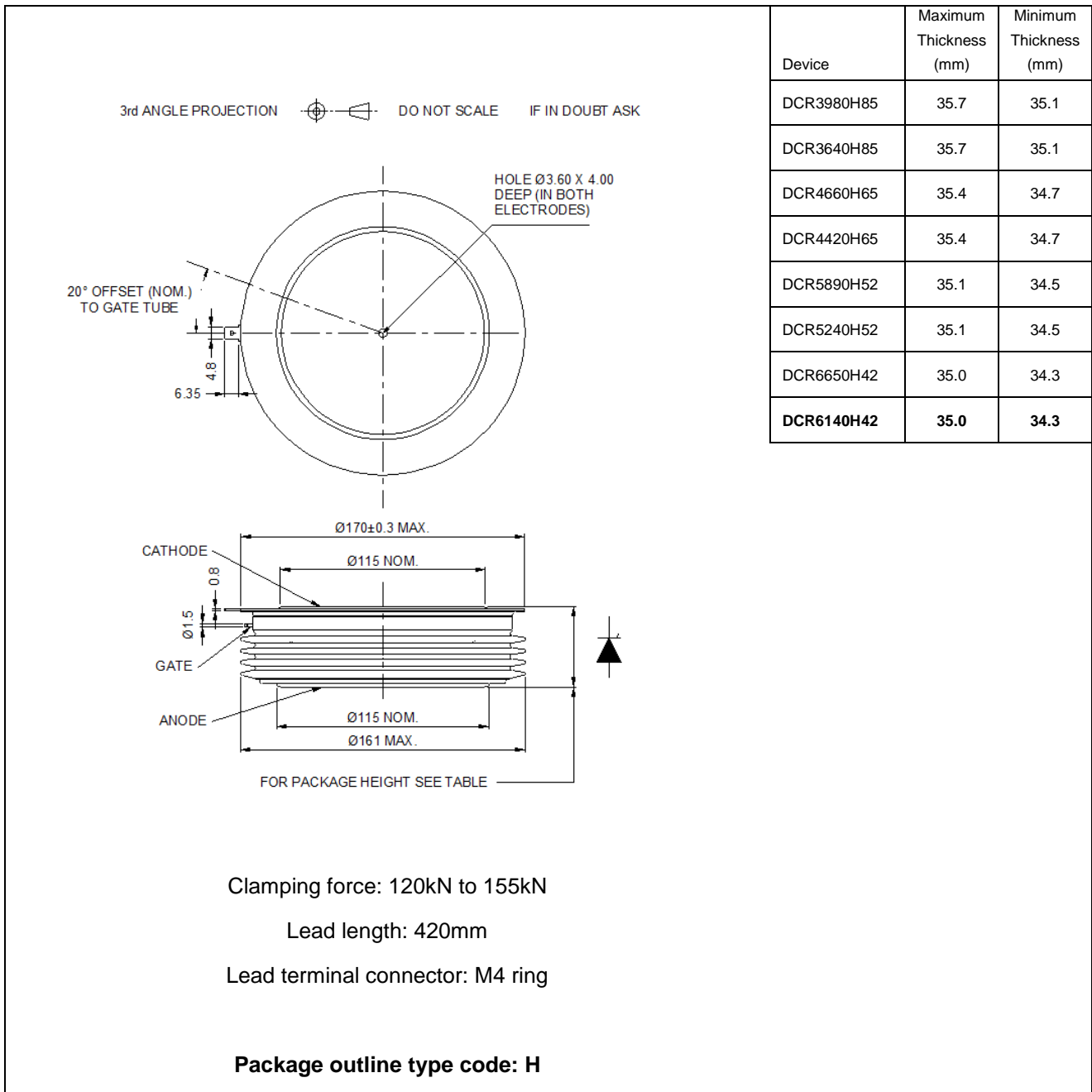


Fig. 16 Package outline

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